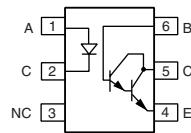
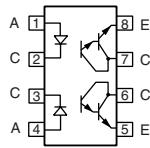


Optocoupler, Photodarlington Output (Single, Dual, Quad Channel)

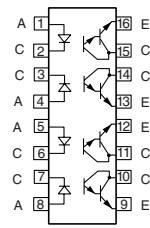
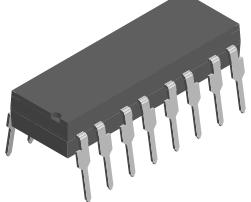
Single Channel



Dual Channel



Quad Channel



i179011

FEATURES

- 125 mA load current rating
- Fast rise time, 10 µs
- Fast fall time, 35 µs
- Single, dual and quad channel
- Solid state reliability
- Standard DIP packages
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


RoHS
COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- BSI IEC 60950 IEC 60065
- FIMKO

DESCRIPTION

The IL30/IL31/IL55 single, ILD30/ILD31/ILD55 dual, and ILQ30/ILQ31/ILQ55 quad are optically coupled isolators with gallium arsenide infrared emitters and silicon photodarlington sensors. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits, with no crosstalk between channels. These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

The IL30/IL31/IL55 are equivalent to MCA230/MCA231/MCA255. The ILD30/ILD31/ILD55 are designed to reduce board space requirements in high density applications.

ORDER INFORMATION

PART	REMARKS
IL30	CTR > 100 %, single channel DIP-6
IL31	CTR > 200 %, single channel DIP-6
IL55	CTR > 100 %, single channel DIP-6
ILD30	CTR > 100 %, dual channel DIP-8
ILD31	CTR > 200 %, dual channel DIP-8
ILD55	CTR > 100 %, dual channel DIP-8
ILQ30	CTR > 100 %, quad channel DIP-16
ILQ31	CTR > 200 %, quad channel DIP-16
ILQ55	CTR > 100 %, quad channel DIP-16
IL55-X009	CTR > 100 %, single channel SMD-6 (option 9)
ILD30-X009	CTR > 100 %, dual channel SMD-8 (option 9)
ILD31-X007	CTR > 200 %, dual channel SMD-8 (option 7)
ILD31-X009	CTR > 200 %, dual channel SMD-8 (option 9)

ORDER INFORMATION

PART	REMARKS
ILD55-X007	CTR > 100 %, dual channel SMD-8 (option 7)
ILD55-X009	CTR > 100 %, dual channel SMD-8 (option 9)
ILQ30-X009	CTR > 100 %, quad channel SMD-16 (option 9)
ILQ55-X007	CTR > 100 %, quad channel SMD-16 (option 7)
ILQ55-X009	CTR > 100 %, quad channel SMD-16 (option 9)

Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Peak reverse voltage			V _{RM}	3.0	V
Forward continuous current			I _F	60	mA
Power dissipation			P _{diss}	100	mW
Derate linearly from 25 °C				1.33	mW/°C
OUTPUT					
Collector emitter breakdown voltage		IL30	BV _{CEO}	30	V
		ILD30	BV _{CEO}	30	V
		ILQ30	BV _{CEO}	30	V
		IL55	BV _{CEO}	55	V
		ILD55	BV _{CEO}	55	V
		ILD55	BV _{CEO}	55	V
Collector (load) current			I _C	125	mA
Power dissipation			P _{diss}	150	mW
Derate linearly from 25 °C				2.0	mW/°C
COUPLER					
Total package power dissipation		IL30	P _{tot}	250	mW
		IL31	P _{tot}	250	mW
		IL55	P _{tot}	250	mW
		ILD30	P _{tot}	400	mW
		ILD31	P _{tot}	400	mW
		ILD55	P _{tot}	400	mW
		ILQ30	P _{tot}	500	mW
		ILQ31	P _{tot}	500	mW
		ILQ55	P _{tot}	500	mW
Derate linearly from 25 °C		IL30		3.3	mW/°C
		IL31		3.3	mW/°C
		IL55		3.3	mW/°C
		ILD30		5.33	mW/°C
		ILD31		5.33	mW/°C
		ILD55		5.33	mW/°C
		ILQ30		6.67	mW/°C
		ILQ31		6.67	mW/°C
		ILQ55		6.67	mW/°C
Isolation test voltage			V _{ISO}	5300	V _{RMS}
Creepage distance				≥ 7.0	mm
Clearance distance				≥ 7.0	mm
Comparative tracking index			CTI	175	
Storage temperature			T _{stg}	- 55 to + 125	°C



IL30/IL31/IL55/ILD30/ILD31/ILD55/ILQ30/ILQ31/ILQ55

Optocoupler, Photodarlington Output
(Single, Dual, Quad Channel)

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
COUPLER					
Operating temperature		T _{amb}		- 55 to + 100	°C
Lead soldering time at 260 °C				10	s

Note

T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 20 mA	V _F		1.25	1.5	V
Reverse current	V _R = 3.0 V	I _R		0.1	10	µA
Capacitance	V _R = 0 V	C _O		25		pF
OUTPUT						
Collector emitter breakdown voltage	I _C = 100 µA	BV _{CEO}	30/55			V
Collector emitter leakage current	V _{CE} = 10 V, I _F = 0 A	I _{CEO}		1.0	100	nA
Collector emitter capacitance	V _{CE} = 10 V, f = 1.0 MHz	C _{CE}		3.4		pF
COUPLER						
Collector emitter saturation voltage	I _C = 50 mA, I _F = 50 mA	V _{CEsat}		0.9	1.0	V
Isolation test voltage			5300			V _{RMS}
Isolation resistance		R _{IO}		10 ¹²		Ω
Capacitance (input to output)		C _{IO}		0.5		pF

Note

T_{amb} = 25 °C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	I _F = 10 mA, V _{CE} = 5.0 V	IL30	CTR	100	400		%
		IL55	CTR	100	400		%
		ILD30	CTR	100	400		%
		ILD55	CTR	100	400		%
		ILQ30	CTR	100	400		%
		ILQ55	CTR	100	400		%
		IL31	CTR	200	400		%
		ILD31	CTR	200	400		%
		ILQ31	CTR	200	400		%

SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	V _{CC} = 13.5 V, I _F = 50 mA, R _L = 100 Ω	t _r		10		µs
Fall time	V _{CC} = 13.5 V, I _F = 50 mA, R _L = 100 Ω	t _f		35		µs

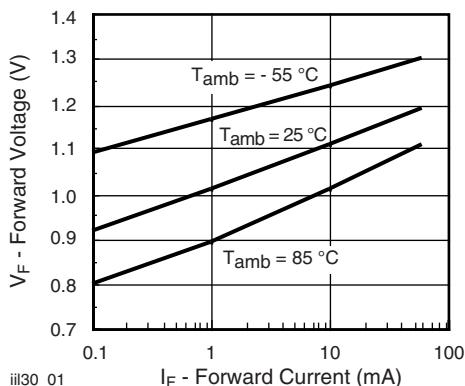
TYPICAL CHARACTERISTICS $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Fig. 1 - Forward Voltage vs. Forward Current

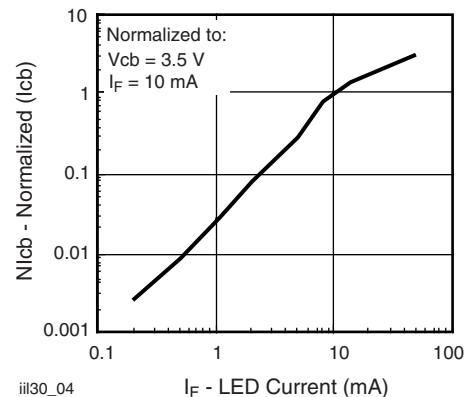


Fig. 4 - Normalized Collector Base Photocurrent vs. LED Current

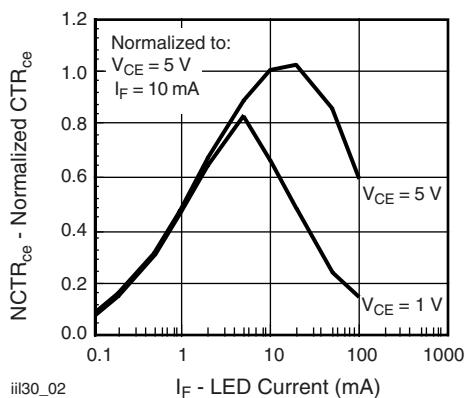
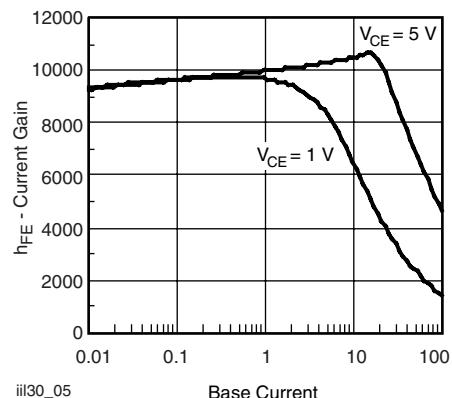
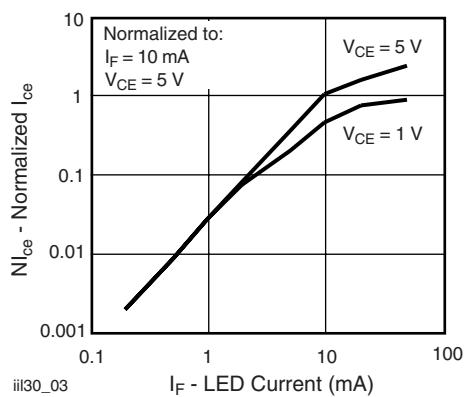
Fig. 2 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED CurrentFig. 5 - h_{FE} Current Gain vs. Base Current

Fig. 3 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

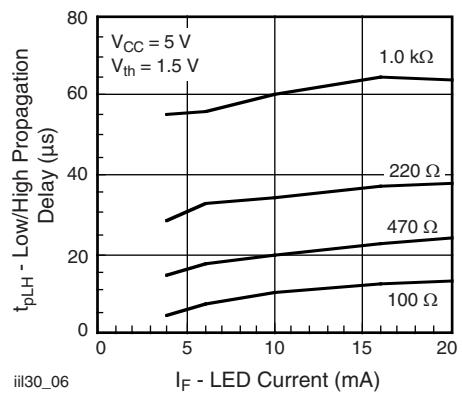


Fig. 6 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

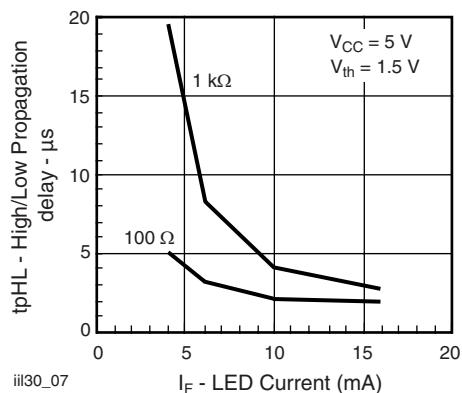
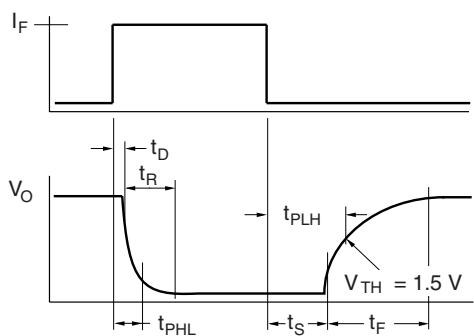
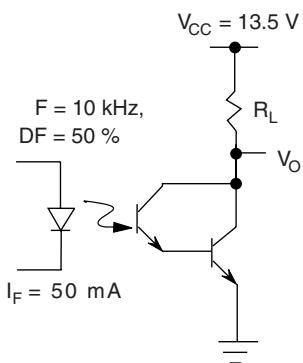


Fig. 7 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current



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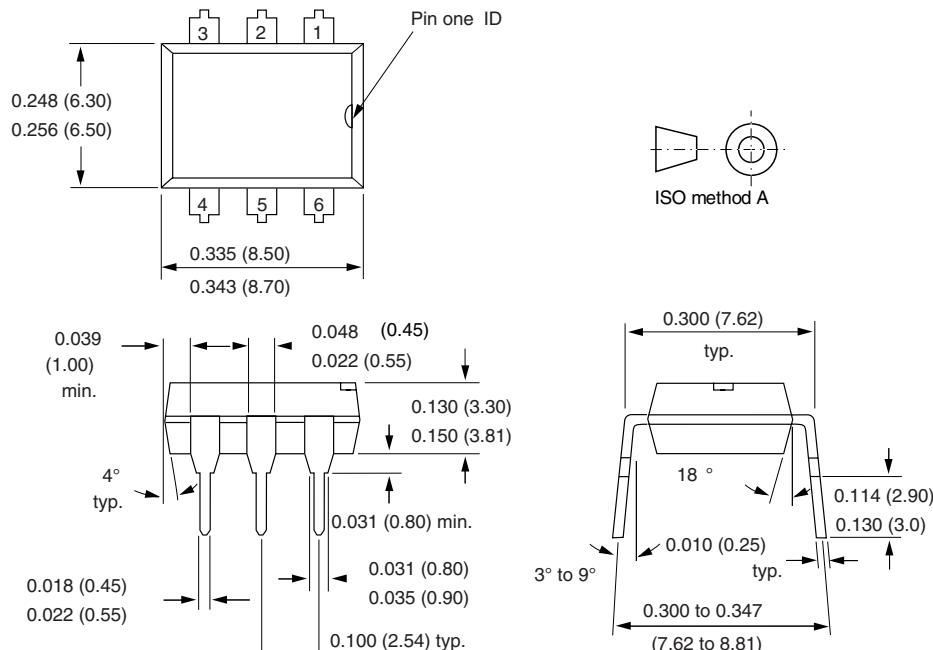
Fig. 8 - Switching Waveform



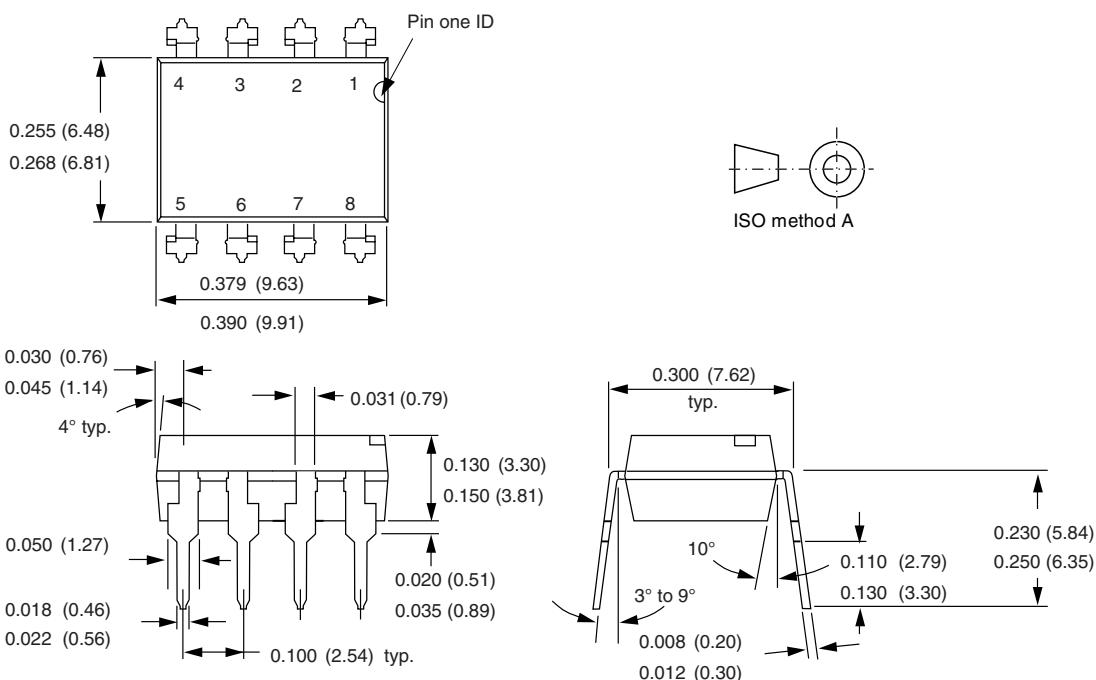
iii30_09

Fig. 9 - Switching Schematic

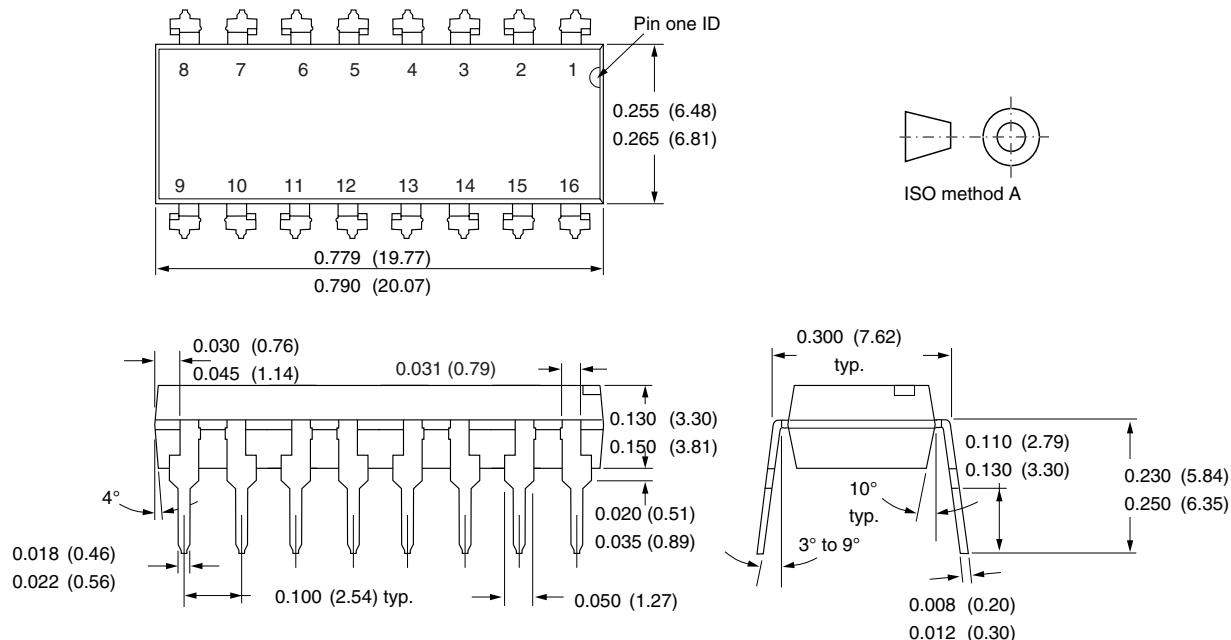
PACKAGE DIMENSIONS in inches (millimeters)



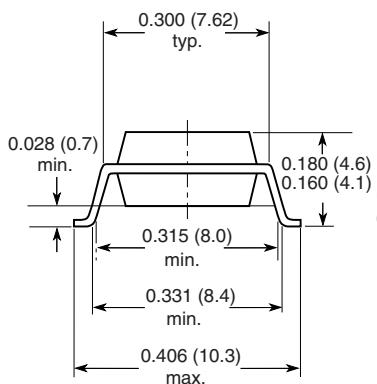
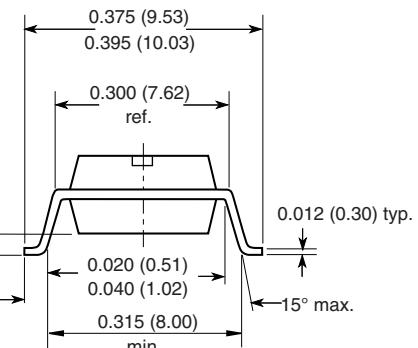
j178004



i178006

PACKAGE DIMENSIONS in inches (millimeters)


i178007

Option 7**Option 9**

18494

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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